Vertical Cavity Surface Emitting Laser in ST Optical Sub-Assembly



OPV315AT, OPV315BT, OPV315YAT, OPV315YBT

Technical Data

Features

- 850 nm VCSEL technology
- High thermal stability
- Up to 2.5 Gbps
- Recommended for multimode fiber applications
- Microbead lens
- Pin out and attenuation options available on request
- Burned in for communication level reliability
- High optical coupling to MM fiber
- ST* style receptacle



Description

The OPV315AT and OPV315BT are high performance 850nm VCSEL packaged for high speed communication links. OPV315AT and OPV315BT combines all the performance advantages of a VCSEL with the addition of a power monitor diode for precise control of optical power.

The OPV315YAT and OPV315YBT are identical electrically and optically and differ only in pin out. Refer to mechanical drawings for details.

This product's combination of features including high speed, high output power and concentric beam make it an ideal transmitter for integration into all types of data communications equipment.

Applications include:

- ♦ Fibre Channel
- ♦ Gigabit Ethernet
- ◆ ATM
- VSR (Very Short Reach)
- Intra-system links
- Optical backplane interconnects.

Absolute Maximum Ratings (T_A = 25 ° C unless otherwise noted)

Storage Temperature	-40°C to +125°C
Operating Temperature	-40°C to +85°C
Soldering Lead Temperature	260°C for 10 Seconds
Maximum Forward Peak Current	30 mA
Maximum Reverse Voltage	5 V



Additional laser safety information can be found on the Optek website. See application #221. Classification is not marked on the device due to space limitations. See package outline for centerline of optical radiance. Operating devices beyond maximum rating may cause devices to exceed rated classification

* - ST is a registered trademark of AT&T

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Electrical/Optical Characteristics (at 25 °C unless otherwise specified)

SYMBOL	PARAMETER		MIN TYP		UNITS	TEST CONDITION
P _{T50}	Total Coupled Power OPV315AT, OPV315YA	т 300			μW	$I_F = 7 \text{ mA}$
	50/125 μm Fiber OPV315BT, OPV315YE	т 200			μW	$I_F = 7 \text{ mA}$
I _{TH}	Threshold Current	0.8		3.0	mA	Note1
V_{F}	Forward Voltage	1.6		2.2	V	$I_F = 7 \text{ mA}$
I _R	Reverse Current			35	nA	$V_R = 5 V$
Rs	Series Resistance	20		55	ohms	Note 2
η	Slope Efficiency OPV315AT, OPV315Y/	т 30			μW/mA	Note 3
	OPV315BT, OPV315Y	BT 20			μW/mA	Note 3
I _{RPD}	Reverse Current, photo diode			35	nA	V _R = 40 V
	Linearity	0.00				Note 4
I _M	Monitor Current	30			μΑ	$I_F = 7 \text{ mA}, V_R = 5 \text{ V}$
λ	Wavelength	840		856	nm	
Δλ	Optical Bandwidth			0.85	nm	
t _r	Rise Time		90		ps	20% to 80%
t _f	Fall Time		120		ps	80% to 20%
N_{RI}	Relative Intensity Noise		-123		db/Hz	
Δη/ΔΤ	Temp Coefficient of Slope Efficiency		-0.5		%/℃	(0°-70°C)
$\Delta I_{TH}/\Delta T$	Temp Coefficient of Threshold Current		±0.1		mA	0°-70°C
Δλ/ΔΤ	Temp Coefficient of Wavelength		0.06		nm/℃	0°-70°C
ΔVf/ΔT	Temperature Coefficient for VF		-2.5		mV/℃	

NOTES:

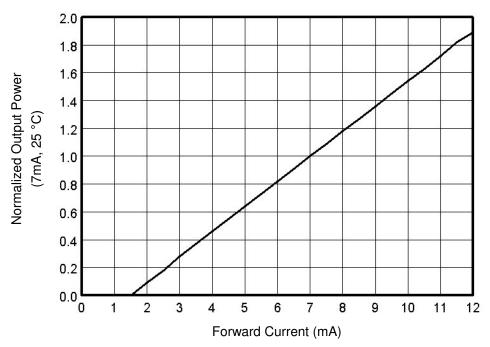
- (1) Threshold Current is based on the two line intersection method specified in Telcordia GR-468-Core. Line 1 from 4 mA to 6 mA. Line 2 from 0 mA to 0.5 mA.
- (2) Series Resistance is the slope of the Voltage-Current line from 5 to 8 mA.
- (3) Slope efficiency, is the slope of the best fit LI line from 5 mA to 8 mA using no larger than .25 mA test interval points. Measured with a 50/125 µm fiber.
- (4) Linearity—Using data points taken for slope efficiency above, data L/delta I shall be calculated for each adjacent pair of points.

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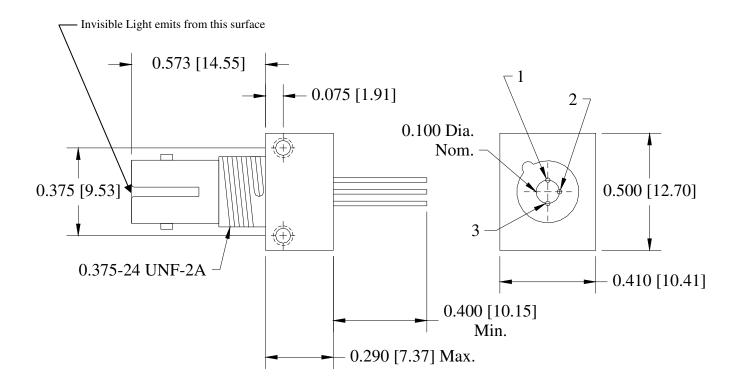


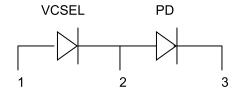
Normalized Output Power vs. Forward Current



OPV315AT, OPV315BT, OPV315YAT, OPV315YBT Technical Data







VCSEL		PD	
		N	
1	2		3

OPV315AT, OPV315BT				
Pin	Connection			
1	VCSEL Anode			
2	VCSEL Cathode/PD Anode			
3	PD Cathode			

OPV315YAT, OPV315YBT		
Pin	Connection	
1	VCSEL Cathode	
2	VCSEL Anode/PD Cathode	
3	PD Anode	

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